


**SD100-12-22-021**
**2.5mm Dia. Blue-Enhanced Photodiode**

**FEATURES**

- Low Noise
- Blue-Enhanced
- High Shunt Resistance
- High Response

**DESCRIPTION**

The **SD100-12-22-021** is a 2.5mm diameter blue-enhanced silicon PIN photodiode, packaged in a hermetic TO-5 metal package.

**APPLICATIONS**

- Instrumentation
- Industrial
- Medical

**> Absolute Maximum Ratings**

| Part No.        | Wavelength Range [nm] | Reverse Voltage [V] | Operating Temperature [C] | Storage Temperature [C] | Package |
|-----------------|-----------------------|---------------------|---------------------------|-------------------------|---------|
| SD100-12-22-021 | 350 to 1100           | 75                  | -40 to +100               | -55 to +125             | TO-5    |

**> Typical Electrical and Optical Characteristics**

| Typical Characteristics (T=23°C unless specified) |                                   |           |      |                       |      |       |
|---|-----------------------------------|-----------|------|-----------------------|------|-------|
| Parameter   | Test Conditions                   | Symbol    | Min  | Typical               | Max  | Unit  |
| Dark Current                                      | $V_R = 50V$                       | $I_D$     | -    | 1.6                   | 6.4  | nA    |
| Junction Capacitance                              | $V_R = 0V, f = 1 \text{ MHz}$     | $C_J$     | 300  | -                     | -    | pF    |
|   | $V_R = 50V, f = 1 \text{ MHz}$    |           | -    | 87                    | -    |       |
| Spectral Application Range                        | Spot Scan                         | $\lambda$ | 350  | 26                    | 1100 | nm    |
| Responsivity                                      | $\lambda=450\text{nm}, V_R=0V$    | $R$       | 0.20 | -                     | -    | A/W   |
| Breakdown Voltage                                 | $I = 10 \mu A$                    | $V_{BD}$  | 25   | -                     | -    | V     |
| Noise Equivalent Power                            | $V_R = 5V @ \lambda=950\text{nm}$ | NEP       | -    | $4.2 \times 10^{-14}$ | -    | W/√Hz |
| Response Time**                                   | $RL = 50\Omega, V_R = 0V$         | $T_R$     | -    | 190                   | -    | nS    |
|   | $RL = 50\Omega, V_R = 50V$        |           | -    | 13                    | -    |       |

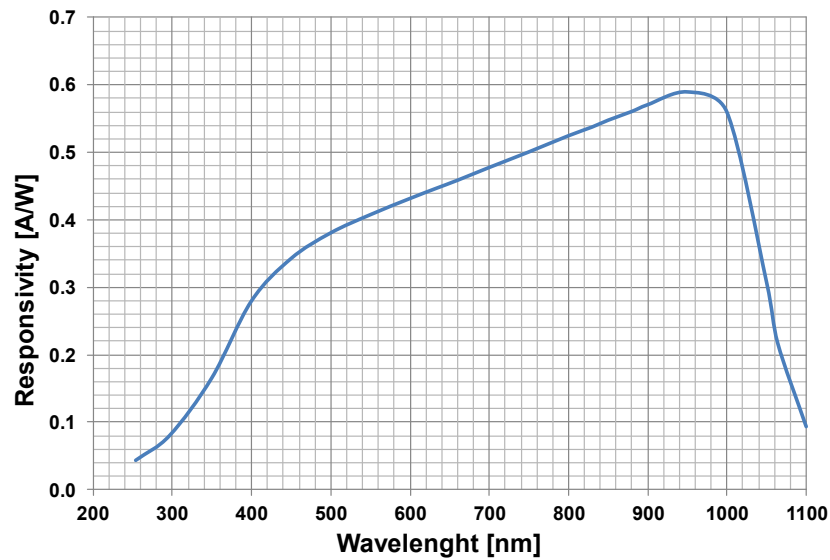
\*\*Response time of 10% to 90% is specified at 660nm wavelength light.

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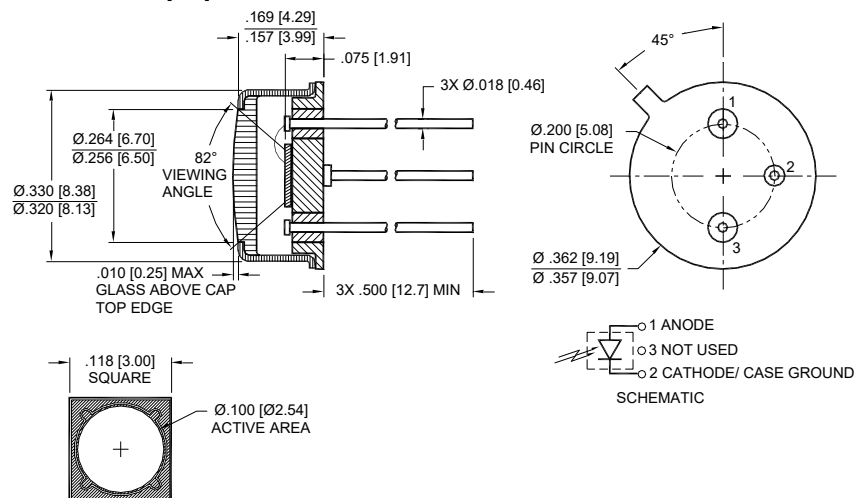
Blue-Enhanced Silicon Photodiode

### > Typical Spectral Response



### > Mechanical Specifications

Units are in inches [mm]



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## MATERIALS SAFETY

This product is free of conflict minerals and meets REACH compliance. Please see website for reports.

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